

Vishay High Power Products

Standard Recovery Diodes (Stud Version), 6 A

FEATURES



DO-203AA (DO-4)

PRODUCT SUMMARY			
I _{F(AV)}	6 A		

- · High surge current capability
- Avalanche types available
- · Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- · RoHS compliant

TYPICAL APPLICATIONS

- Converters
- · Power supplies
- · Machine tool controls
- · Battery charges

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		6	A	
	T _C	160	°C	
I _{F(RMS)}		9.5	A	
I _{FSM}	50 Hz	159	٨	
	60 Hz	167	Α	
l ² t	50 Hz	134	A ² s	
	60 Hz	141	A-5	
V _{RRM}	Range	100 to 1200	V	
T _J		- 65 to 175	°C	

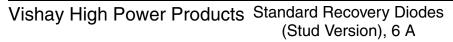
ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{R(BR)} , MINIMUM AVALANCHE VOLTAGE V ⁽¹⁾	I _{RRM} MAXIMUM AT T _J = 175 °C mA	
	10	100	150	-		
	20	200	275	-		
	40	400	500	500		
6F(R) 60 80 100	60	600	725	750	12	
	80	800	950	950		
	100	1000	1200	1150		
	120	1200	1400	1350		

Document Number: 93519 Revision: 29-Sep-08

 $^{^{(1)}}$ Avalanche version only available from V_{RRM} 400 V to 1200 V

6F(R) Series





PARAMETER	SYMBOL	. TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave		6 160	A °C	
Maximum RMS forward current	I _{F(RMS)}			9.5	A	
Maximum non-repetitive peak reverse power	P _R (1)	10 μs square pulse, T _J = T _J maximum		4	K/W	
		t = 10 ms	No voltage	Sinusoidal half wave, initial T _J = T _J maximum	159	Α
Maximum peak, one cycle forward,		t = 8.3 ms	reapplied		167	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM} reapplied		134	
		t = 8.3 ms			141	
		t = 10 ms	No voltage		127	A ² s
Maximum 12t for fusing	I ² t	t = 8.3 ms	reapplied		116	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		90	
		t = 8.3 ms	reapplied		82	
Maximum $I^2 \sqrt{t}$ for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		1270	A²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.63	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.86	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum		15.7	mΩ	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			5.6	1115.2
Maximum forward voltage drop	V_{FM}	$I_{pk} = 19 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu \text{s} \text{ rectangular wave}$			1.10	V

Note

 $^{^{(1)}}$ Available only for avalanche version, all other parameters the same as 6F

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	T_J		- 65 to 175	°C	
Maximum storage temperature range	T _{Stg}		- 65 to 200	C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5	FC/VV	
Mounting torque, ± 10 %		Lubricated threads (Not lubricated threads)	1.2 (1.5)	N ⋅ m (lbf ⋅ in)	
Annyayimata wajaht			7	g	
Approximate weight			0.25	OZ.	
Case style		See dimensions - link at the end of datasheet	pt DO-203AA (DO-4)		



Standard Recovery Diodes Vishay High Power Products (Stud Version), 6 A

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.34	0.29			
120°	0.44	0.48			
90°	0.57	0.63	$T_J = T_J \text{ maximum}$	K/W	
60°	0.85	0.88			
30°	1.37	1.39			

Note

The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

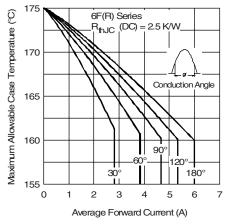


Fig. 1 - Current Ratings Characteristics

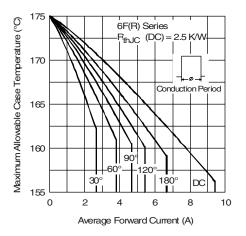


Fig. 2 - Current Ratings Characteristics

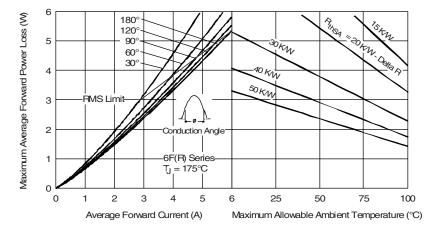


Fig. 3 - Forward Power Loss Characteristics

Vishay High Power Products Standard Recovery Diodes (Stud Version), 6 A



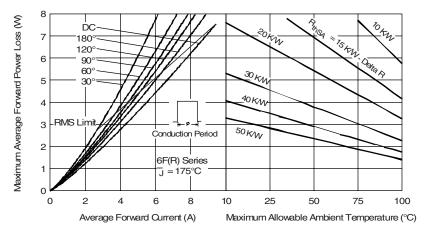


Fig. 4 - Forward Power Loss Characteristics

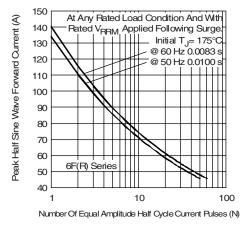


Fig. 5 - Maximum Non-Repetitive Surge Current

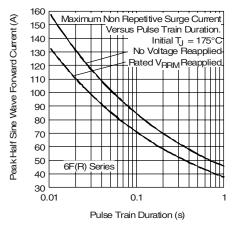


Fig. 6 - Maximum Non-Repetitive Surge Current

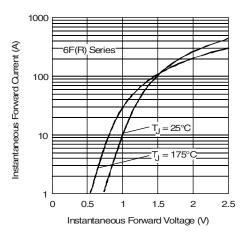


Fig. 7 - Forward Voltage Drop Characteristics

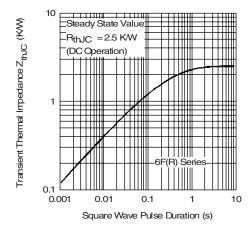


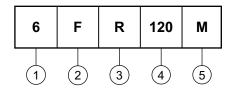
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Standard Recovery Diodes Vishay High Power Products (Stud Version), 6 A

ORDERING INFORMATION TABLE

Device code



- Current rating: Code = I_{F(AV)}
- 2 F = Standard device
- None = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 5 None = Stud base DO-203AA (DO-4) 10-32UNF-2A
 - M = Stud base DO-203AA (DO-4) M5 x 0.8 (not available for avalanche diode)

LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95311	

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1